

The Comparison of Property and Visible Light Activity between Bulk and Surface Doped N-TiO₂ Prepared by Sol-gel and N₂-plasma Treatment

Shaozheng Hu,* Fayun Li, and Zhiping Fan

Institute of Eco-environmental Sciences, Liaoning Shihua University, Fushun 113001, PR China

*E-mail: hushaozheng001@163.com

Received August 19, 2011, Accepted November 15, 2011

A modified sol-gel method and N₂-plasma treatment were used to prepare bulk and surface doped N-TiO₂, respectively. XRD, TEM, UV-vis spectroscopy, N₂ adsorption, Elemental Analyzer, Photoluminescence, and XP spectra were used to characterize the prepared TiO₂ samples. The N doping did not change the phase composition and particle sizes of TiO₂ samples, but increased the visible light absorption. The photocatalytic activities were tested in the degradation of an aqueous solution of a reactive dyestuff, methylene blue, under visible light. The photocatalytic activity of surface doped N-TiO₂ prepared by N₂-plasma was much higher than that of bulk doped N-TiO₂ prepared by sol-gel method. The possible mechanism for the photocatalysis was proposed.

Key Words : TiO₂, Photocatalysis, Bulk doping, Surface doping, N₂-plasma

Introduction

Photocatalysis has been widely used in energy conversion, air purification, and organic contaminant mineralization.^{1,2} Titanium dioxide (TiO₂), a kind of typical photocatalyst, has attracted extensive interest because of its high activity, low cost, and long-time stability. However, TiO₂ only becomes active under irradiation with ultraviolet (UV) light. Thus, many efforts have been devoted recently to improve the optical response of TiO₂ in the visible region.

Among the TiO₂ modification methods, N doping is one of the most effective. In 2001, Asahi *et al.*³ prepared nitrogen doped TiO₂ films by sputtering TiO₂ in a N₂/Ar gas mixture, and concluded that the doped N atoms narrowed the band gap of TiO₂ by mixing N 2p and O 2p states, therefore demonstrating the activity for the decomposition of acetone and methylene blue. Since then, N-doping has become a hot topic and been widely investigated. Heating TiO₂ powders in N₂ and/or NH₃ at elevated temperatures is the conventional method to prepare nitrogen-doped TiO₂.³ Besides the energy waste, the treatment at such high temperature usually results in the low surface area due to grain growth, which would decrease the number of photoactive sites. Therefore, new strategies for preparing nitrogen-doped TiO₂, such as sputtering,⁴ sol-gel,⁵ ion implantation,⁶ pulsed laser deposition,⁷ hydrothermal synthesis,⁸ and plasma treatment⁹ have been proposed more recently.

Non-thermal plasma is composed of atoms, ions and electrons, which are much more reactive than their molecule precursors. Plasma is able to initiate a lot of reactions, which take place efficiently only at elevated temperatures and high pressures, under mild conditions. So far, some literatures on preparation of N doped TiO₂ by plasma treatment have been reported.⁹⁻¹² Yamada *et al.*^{10,11} investigated the photocatalytic activity of TiO₂ thin films prepared by plasma treatment

using N₂ as nitrogen source. They suggested that the substitutional N-doping contributed to the band-gap narrowing, therefore absorbing visible light and demonstrating the photocatalytic activity. Abe *et al.*¹² prepared N doped TiO₂ by NH₃(10%)/Ar plasma. The influence of the NH₃/Ar gas pressures (50, 300 and 1000 Pa) on the physical and photocatalytic property of the powder was investigated.

It is known that plasma treatment is a kind of surface modification. Thus, it is deduced that the doping N atoms is mainly in the surface layer of TiO₂ samples prepared by plasma treatment. However, for the sol-gel method, the nitrogen source and titanium source mix sufficiently during the preparation process, leading to the N atoms doped mainly in the bulk TiO₂. Therefore, there are two N doping states existed in the N-doped TiO₂, bulk doping and surface doping. Such different doping state maybe influence the property and visible light activity of the prepared samples. Whereas, few literature on the comparison of property and visible light activity between bulk and surface doped N-TiO₂ was reported. In this work, a modified sol-gel method and N₂-plasma treatment method were used to prepare bulk and surface doped N-TiO₂, respectively. The structural and optical properties of prepared N doped TiO₂ were investigated. The photocatalytic performances of prepared samples were evaluated in the degradation of methylene blue under visible light.

Experimental

Preparation and Characterization. A modified sol-gel method was used to synthesize bulk doped N-TiO₂ (mole ratio of 1:20:1:1:1 for TTIP:EtOH:HNO₃:H₂O:urea). First, TTIP was dissolved in EtOH under stirring for 30 min to form solution A. EtOH was mixed with H₂O which contained HNO₃ to form solution B. After mixing both solutions,

precipitation readily occurred. Then the urea was added dropwisely. The obtained homogeneous transparent solution was stirred at 5 °C for 30 min and dried at 100 °C for 3 h. The powder was collected and calcined at 400 °C for 3 h. The obtained N-doped TiO₂ was denoted as N1-TiO₂. For comparison, U-TiO₂ was prepared by the same procedure above but in the absence of urea.

The surface doped N-TiO₂ was conducted in a dielectric barrier discharge (DBD) reactor, consisting of a quartz tube and two electrodes. The high-voltage electrode was a stainless-steel rod (2.5 mm), which was installed in the axis of the quartz tube and connected to a high voltage supply. The grounding electrode was an aluminum foil which was wrapped around the quartz tube. For each run, 0.4 g U-TiO₂ was charged into the quartz tube. At a constant N₂ flow (20 mL min⁻¹), a high voltage of 9-11 kV was supplied by a plasma generator at an overall power input of 50 V × 0.4 A. The discharge frequency was fixed at 10 kHz, and the discharge was kept for 10 min. After discharge, the reactor was cooled down to room temperature. The obtained TiO₂ sample was denoted as N2-TiO₂.

XRD patterns of the prepared TiO₂ samples were recorded on a Rigaku D/max-2400 instrument using Cu-K α radiation ($\lambda = 1.54 \text{ \AA}$). TEM images were measured using a Philips Tecnai G220 model microscope. UV-vis spectroscopy measurement was carried out on a JASCO V-550 model UV-vis spectrophotometer, using BaSO₄ as the reflectance sample. Doping N content in the bulk was analyzed by using Elemental Analyzer (vario MACRO cube). XPS measurements were conducted on a Thermo Escalab 250 XPS system with Al K α radiation as the exciting source. The binding energies were calibrated by referencing the C 1s peak (284.6 eV) to reduce the sample charge effect. Nitrogen adsorption was measured at -196 °C on a Micromeritics 2010 analyzer. All the samples were degassed at 393 K before the measurement. BET Surface area (S_{BET}) was calculated according to the adsorption isotherm. Photoluminescence (PL) spectra were measured at room temperature with a fluorospectrophotometer (FP-6300) using an Xe lamp as excitation source.

Photocatalytic Reaction. Methylene blue (MB) was selected as model compound to evaluate the photocatalytic performance of the prepared TiO₂ particles in an aqueous solution under visible light irradiation. 0.1 g TiO₂ powders were dispersed in 100 mL aqueous solution of MB (initial concentration $C_0 = 50 \text{ ppm}$) in an ultrasound generator for 10 min. The suspension was transferred into a self-designed glass reactor, and stirred for 30 min in darkness to achieve the adsorption equilibrium. The concentration of MB at this point was considered as the absorption equilibrium concentration C_0 . The adsorption capacity of a catalyst to MB was defined by the adsorption amount of MB on the photocatalyst ($C_0 - C_t$). In the photoreaction under visible light irradiation, the suspension was exposed to a 110-W high-pressure sodium lamp with main emission in the range of 400-800 nm, and air was bubbled at 130 mL/min through the solution. The UV light portion of sodium lamp was

filtered by 0.5 M NaNO₂ solution.¹³ All runs were conducted at ambient pressure and 30 °C. At given time intervals, 4 mL suspension was taken and immediately centrifuged to separate the liquid samples from the solid catalyst. The concentrations of MB before and after reaction were measured by means of a UV-vis spectrophotometer at a wavelength of 665 nm. The percentage of degradation $D\%$ was determined as follows:

$$D\% = \frac{A_0 - A}{A_0} \times 100\% \quad (1)$$

Where A_0 and A are the absorbances of the liquid sample before and after degradation, respectively.

Results and Discussion

It is reported that the phase composition and particle size of TiO₂ have significant influence on its photocatalytic activity.² The XRD patterns of the U-TiO₂, N1-TiO₂ and N2-TiO₂ (Fig. 1) indicated that all TiO₂ samples are pure anatase phase. The particle sizes which calculated by their XRD patterns according to the Debye-Scherrer equation are 24.5, 25.1, and 24.3 nm for U-TiO₂, N1-TiO₂, and N2-TiO₂. This result indicates that no remarkable changes is observed in particle sizes.

Figure 2 shows the representative TEM images of N1-TiO₂ (left) and N2-TiO₂ (right). The prepared N doped TiO₂ samples exhibited the small particle sizes around 20-30 nm, which is consistent with the XRD result. Besides, it is shown that N1-TiO₂ exhibited a much narrower particle size distribution compared with that of N2-TiO₂. This indicated that bulk doping of TiO₂ is favorable for the formation narrow particle size distribution.

Up to date, the mechanism of the enhancement by N-doping is still controversial. Asahi *et al.*³ concluded that the doped N atoms narrowed the band gap of TiO₂ by mixing N 2p and O 2p states, therefore demonstrating the activity. Irie *et al.*¹⁴ argued that the isolated narrow band located above the valence band is responsible for the visible light response. Lee *et al.*¹⁵ suggested that substitutional N-doping would

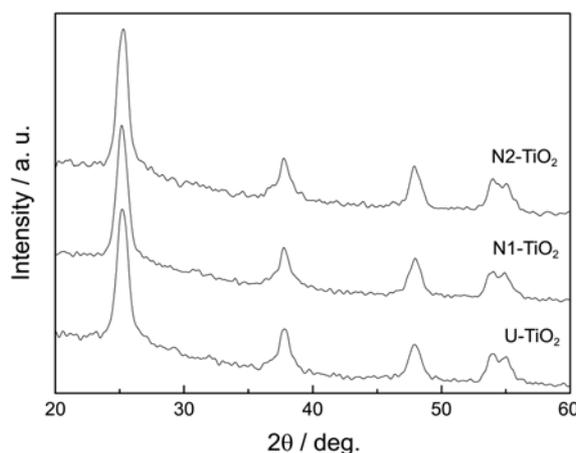


Figure 1. XRD patterns of U-TiO₂ and prepared N-doped TiO₂ samples.

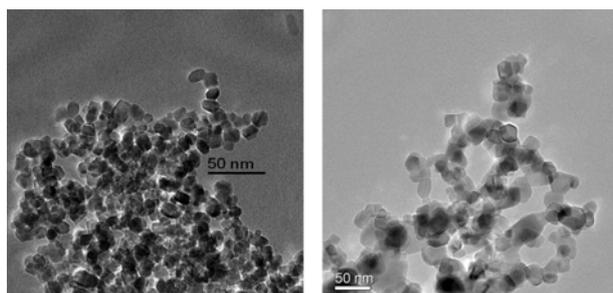


Figure 2. TEM images of N1-TiO₂ (left) and N2-TiO₂ (right).

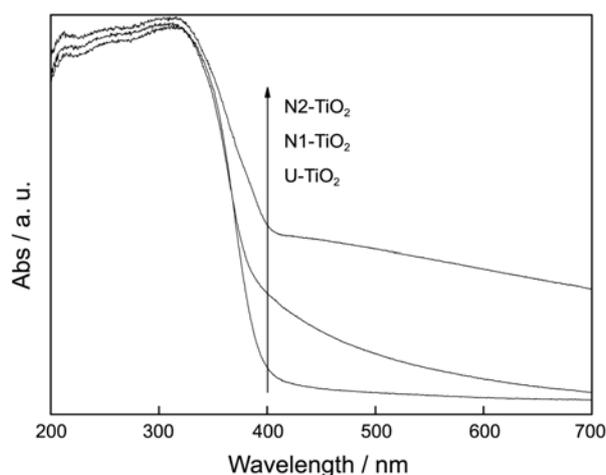


Figure 3. UV-vis spectra of U-TiO₂ and prepared N-doped TiO₂ samples.

narrow the band gap by the coupling of the O 2p and N 2p orbitals, while interstitial N-doping would create an additional defect state between the conduction band and valence band. The UV-vis diffuse reflectance spectra of prepared samples are shown in Figure 3. Compared with U-TiO₂, obvious shifts of the absorption band into the visible light region were observed for N1-TiO₂ and N2-TiO₂. However, the spectra in the visible region of prepared N-doped TiO₂ samples are obvious different, which is probably due to the different doping N state. In the spectrum of N1-TiO₂, the obvious absorption in 400–550 nm is observed, which is a typical absorption region for N doped TiO₂ materials. This typical absorption is due to the electronic transition from the isolated N 2p level, which is formed by incorporation of nitrogen atoms into the TiO₂ lattice, to the conduction band.¹⁶ This is consistent with the result of Irie.¹⁴ However, in the spectrum of N2-TiO₂, distinct shift of the absorption band into the visible light region were observed. The band-gap energies of TiO₂ samples which calculated according to the method of Oregan and Gratzel¹⁷ indicate that the band-gap energies of U-TiO₂, N1-TiO₂, and N2-TiO₂ are 3.1, 3.1, and 2.7 eV. This indicated that the band gap of N2-TiO₂ was narrowed by N doping which is agreement with the result of Asahi.³ Therefore, it is concluded that the doping N state can be influenced by the preparation method. According to the result of Lee,¹⁵ the substitutional N-doping existed in the surface doped N2-TiO₂, whereas interstitial N-doping exist-

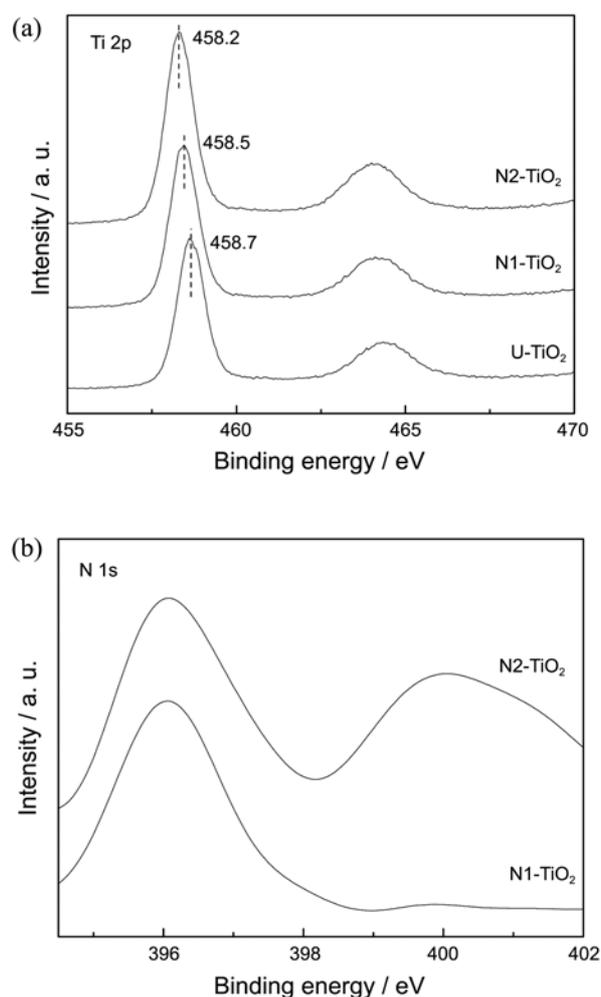


Figure 4. XP spectra of U-TiO₂ and N-doped TiO₂ samples in the region of Ti 2p (a) and N 1s (b).

ed in the bulk doped N1-TiO₂. Besides, the distinct absorption in the whole visible light region is observed in the spectra of N2-TiO₂. Huang *et al.*¹⁸ prepared the visible light responsive TiO₂ by nitrogen-plasma surface treatment, and found the similar broad absorption in visible light region. They suggested that such broad absorption is attributed to the presence of Ti³⁺, which might be formed by plasma treatment.

XPS is an effective surface analysis technique for characterizing elemental composition and chemical states. Figure 4 shows the XP spectra of prepared samples in the region of Ti 2p (A) and N 1s (B). Compared with the spectra of U-TiO₂, slight shifts to lower binding energies were observed for N-doped TiO₂ in the Ti 2p region (Fig. 4(a)). It is known that the binding energy of the element is influenced by its electron density. A decrease in binding energy implies an increase of the electron density. Therefore, This shift is probably attributed to the change of chemical environment after N doping.¹⁹ The electrons of N atoms may be partially transferred from N to Ti, due to the higher electronegativity of oxygen, leading to increased electron densities on Ti atoms. Besides, compared with N1-TiO₂, more shift to lower

Table 1. Summary of physical properties of U-TiO₂ and prepared N-doped TiO₂ samples

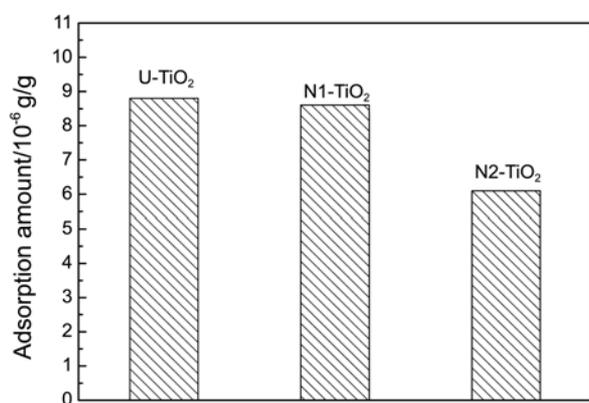
Sample	S _{BET} (m ² g ⁻¹)	Pore volume (cm ³ g ⁻¹)	Central pore size (nm)	^a N _{bulk} (at. %)	^b N _{surface} (at. %)	N _{surface} /N _{bulk}	(O+N)/Ti
U-TiO ₂	71	0.12	3.5	0	0	-	1.99
N1-TiO ₂	67	0.11	3.6	0.69	0.77	1.1	1.95
N2-TiO ₂	70	0.12	3.4	0.66	1.90	2.8	1.85

^{a,b}N_{bulk} and N_{surface} which present the atom percentage of doping N in bulk and surface layer are obtained by the results of Elemental Analyzer and XPS measurement, respectively.

binding energy was observed for N2-TiO₂ (Fig. 4(a)). This is probably due to the presence of Ti ion with low valence (Ti³⁺), which exhibit the higher electron density.

In Figure 4(b), the peaks around 396 and 400 eV are observed in N2-TiO₂ whereas only the peak around 396 eV is observed in N1-TiO₂. According to the previous literatures,^{10,11} they are attributed to the formation of lattice-nitrogen and other surface N species such as N-N and N-O bond. The surface elemental compositions of U-TiO₂ and prepared N-doped TiO₂ samples obtained from XP spectra and Elemental Analyzer were summarized in Table 1. No obvious difference in N_{bulk} is shown between N1-TiO₂ and N2-TiO₂ samples, indicating the total doping N content of two samples is almost same. The N_{surface}/N_{bulk} ratio of N1-TiO₂ is 1.1, indicating the distribution of doping N is almost uniform in the whole sample. However, for N2-TiO₂, the N_{surface}/N_{bulk} ratio is 2.8. This indicates the doping N atoms in N2-TiO₂ sample existed mainly in the surface layer. Besides, the (O+N)/Ti ratio of U-TiO₂ is 1.99. This value decreased after N doping indicating the presence of oxygen vacancies in prepared N doped TiO₂. The (O+N)/Ti ratio of N2-TiO₂ is much lower than that of N1-TiO₂, which indicate more oxygen vacancies were formed by N₂-plasma treatment.

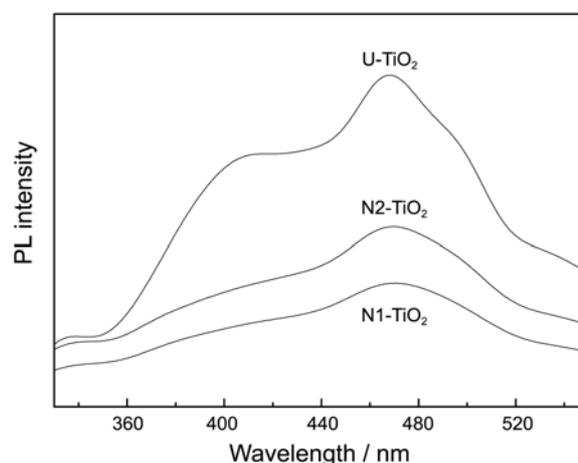
The adsorption of MB on TiO₂-based catalysts was measured by the equilibrium adsorption capacity. No obvious difference in the adsorption capacity was shown between N1-TiO₂ and U-TiO₂, whereas the adsorption capacity of N2-TiO₂ decreased markedly (Fig. 5). The BET specific surface area (S_{BET}), pore volume, and central pore size are listed in Table 1. Compared with U-TiO₂, no obvious decrease

**Figure 5.** Adsorption capacity of MB on U-TiO₂ and N-doped TiO₂ samples.

in S_{BET}, pore volume, and central pore size are shown for the N-doped TiO₂ samples, excluding its influence on the adsorption capacity. Therefore, it is possibly that such decreased adsorption capacity is attributed to the coverage of TiO₂ surface by excess surface N species, leading to the reduced surface sites for adsorbing MB.

PL emission spectra are used to determine the efficiency of trapping, migration, and transfer of a charge carrier, and to understand the fate of electron-hole pairs in semiconductors.²⁰ Figure 6 shows the PL spectra of U-TiO₂ and N-doped TiO₂ samples, using excitation at 300 nm. It is shown that the PL intensities increased in the order: N1-TiO₂ < N2-TiO₂ < U-TiO₂. This phenomena may result from the photoluminescence quenching after N doping. It is known that most of the electrons and holes recombine within a few nanoseconds in the absence of scavengers. If scavengers or surface defects (doping N and oxygen vacancy) are present to trap the electrons or holes, the electron-hole recombination can be suppressed, leading to an enhancement of the subsequent photocatalytic reactions.²¹ Therefore, it is concluded that the electron-hole recombination is restrained by N doping.

The photocatalytic activities of U-TiO₂ and prepared N-doped TiO₂ samples under visible light are shown in Figure 7. It is shown that U-TiO₂ exhibited no activity. After N doping, obvious improvement in photocatalytic activities were observed for N1-TiO₂ and N2-TiO₂. Since no obvious changes were observed in phase compositions and particle sizes between U-TiO₂ and prepared N-doped TiO₂ samples, the enhanced photocatalytic activity must result from the

**Figure 6.** PL spectra of U-TiO₂ and N-doped TiO₂ samples.

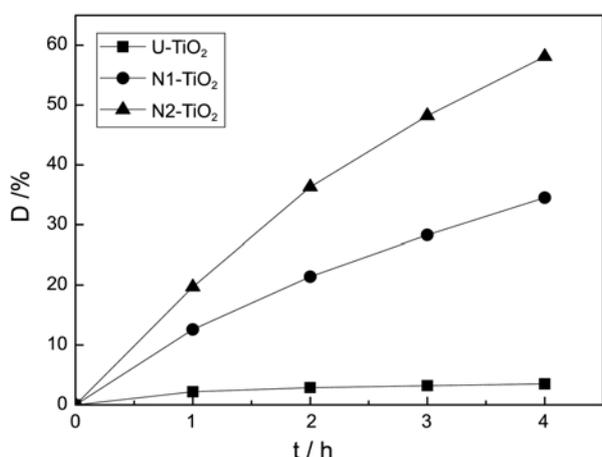


Figure 7. Photocatalytic performances of U-TiO₂ and prepared N-doped TiO₂ samples in the degradation MB under visible light irradiation.

doping of nitrogen in TiO₂, which gave rise to the enhanced absorption in the visible region. Besides, N2-TiO₂ showed much higher activity than that of N1-TiO₂. This may be due to the following reasons. Firstly, the stronger absorption in visible light region of N2-TiO₂ caused the visible light utilization more effectively, thus leading to the much higher activity than that of N1-TiO₂. Secondly, compared with N1-TiO₂, much more doping N in N2-TiO₂ existed on the surface layer (Table 1). Feng *et al.*²² prepared N-doped TiO₂ by heating TiO₂ powders in NH₃ at elevated temperatures, and concluded that the oxygen vacancy (V_o[•]) accompanied with doping N in the surface layer was the surface active site for the visible light photoactivity. In this investigation, the doping N content in the surface layer and oxygen vacancy content of N2-TiO₂ were much higher than that of N1-TiO₂. This probably caused that more surface active sites were formed in N2-TiO₂, leading to its higher photocatalytic activity.

Conclusion

The bulk and surface doped N-TiO₂ were prepared by a modified sol-gel method and N₂-plasma treatment. The N doping did not change the phase composition and particle sizes of TiO₂ samples, but increased the visible light absorption. The doping N states were influenced by the preparation method. The substitutional N-doping existed in the surface doped N2-TiO₂, whereas interstitial N-doping existed in the bulk doped N1-TiO₂. The photocatalytic activity of surface doped N2-TiO₂ prepared by N₂-plasma was much higher than that of bulk doped N1-TiO₂ prepared by sol-gel

method. This is probably due to that the doping N content in the surface layer and oxygen vacancies content of N2-TiO₂ were much higher than that of N1-TiO₂, which caused more surface active sites formed in N2-TiO₂, leading to its higher photocatalytic activity.

Acknowledgments. This work was supported by National Natural Science Foundation of China (No. 41071317, 30972418), National Key Technology R & D Programme of China (No. 2007BAC16B07), the Natural Science Foundation of Liaoning Province (No. 20092080). The authors would like to thank Prof. Anjie Wang, Dalian University of Technology, for the contribution to the manuscript.

References

- Fujishima, A.; Honda, K. *Nature* **1972**, *238*, 37.
- Hoffmann, M. R.; Martin, S. T.; Choi, W.; Bahnemann, D. W. *Chem. Rev.* **1995**, *95*, 69.
- Asahi, R.; Morikawa, T.; Ohwaki, T.; Aoki, A.; Taga, Y. *Science* **2001**, *293*, 269.
- Lindgren, T.; Mwabora, J. M.; Avendano, E.; Jonsson, J.; Hoel, A.; Granqvist, C. G.; Lindquist, S. E. *J. Phys. Chem. B* **2003**, *107*, 5709.
- Qiao, M.; Wu, S. S.; Chen, Q.; Shen, J. *Mater. Lett.* **2010**, *12*, 1398.
- Shen, H.; Mi, L.; Xu, P.; Shen, W. D.; Wang, P. N. *Appl. Surf. Sci.* **2007**, *17*, 7024.
- Zhao, L.; Jiang, Q.; Lian, J. S. *Appl. Surf. Sci.* **2008**, *15*, 4620.
- Hu, S. Z.; Wang, A. J.; Li, X.; Löwe, H. *J. Phys. Chem. Solid* **2010**, *71*, 156.
- Hu, S. Z.; Li, F. Y.; Fan, Z. P. *Appl. Surf. Sci.* **2011**, *258*, 1249.
- Yamada, K.; Yamane, H.; Matsushima, S.; Nakamura, H.; Ohira, K.; Kouya, M.; Kumada, K. *Thin Solid Films* **2008**, *516*, 7482.
- Yamada, K.; Yamane, H.; Matsushima, S.; Nakamura, H.; Sonoda, T.; Miura, S.; Kumada, K. *Thin Solid Films* **2008**, *516*, 7560.
- Abe, H.; Kimitani, T.; Naito, M. *J. Photochem. Photobiol. A* **2006**, *183*, 171.
- Hu, S. Z.; Wang, A. J.; Li, X.; Wang, Y.; Löwe, H. *Chem. Asian J.* **2005**, *5*, 1171.
- Irie, H.; Watanaba, Y.; Hashimoto, K. *J. Phys. Chem. B* **2003**, *107*, 5483.
- Lee, S.; Cho, I.; Lee, D. K.; Kim, D. W.; Noh, T. H.; Kwak, C. H.; Park, S.; Hong, K. S.; Lee, J.; Jung, H. S. *J. Photochem. Photobiol. A* **2010**, *213*, 129.
- Ozaki, H.; Fujimoto, N.; Iwamoto, S.; Inoue, M. *Appl. Catal. B* **2007**, *70*, 431.
- Oregan, B.; Gratzel, M. *Nature* **1991**, *353*, 737.
- Huang, C. M.; Chen, L. C.; Cheng, K. W.; Pan, G. T. *J. Mol. Catal. A* **2007**, *261*, 218.
- Li, H. X.; Li, J. X.; Huo, Y. N. *J. Phys. Chem. B* **2006**, *110*, 1559.
- Cong, Y.; Zhang, J.; Chen, F.; Anpo, M. *J. Phys. Chem. C* **2007**, *111*, 6976.
- Fa, W. J.; Zan, L.; Gong, C. Q.; Zhong, J. C.; Deng, K. J. *Appl. Catal. B* **2008**, *79*, 216.
- Feng, C. X.; Wang, Y.; Jin, Z. S.; Zhang, J. W.; Zhang, S. L.; Wu, Z. S. *New J. Chem.* **2008**, *32*, 1038.